NSN 5961-01-407-7429

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-407-7429 **Inclosure Material:** Metal **Overall Length:** 1.742 inches **Overall Height:** 1.190 inches **Overall Width:** 0.880 inches **Mounting Method: Bracket Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 repetitive peak off-state voltage and 500.0 repetitive peak reverse voltage and 600.0 reverse voltage, total rms **Current Rating Per Characteristic:** 63.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector blank and 2.0 watts small-signal input power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Thyristor mtd to bracket **Special Test Features:** Leakage current iaw (53711) 5905711 **Test Data Document:** 53711-5906193 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 bracket and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No